

# Anil G Khairnar

## List of Publications by Year in descending order

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7  
papers

148  
citations

1684188

5  
h-index

1872680

6  
g-index

8  
all docs

8  
docs citations

8  
times ranked

160  
citing authors

#	ARTICLE	IF	CITATIONS
1	Preparation of rare earth CeO <sub>2</sub> thin films using metal organic decomposition method for metal-oxide semiconductor capacitors. Journal of Materials Science: Materials in Electronics, 2017, 28, 12503-12508.	2.2	11
2	HfO <sub>2</sub> gate dielectric on Ge (1 1 1) with ultrathin nitride interfacial layer formed by rapid thermal NH <sub>3</sub> treatment. Applied Surface Science, 2016, 364, 747-751.	6.1	18
3	High Dielectric Constant ZrO <sub>2</sub> Films by Atomic Layer Deposition Technique on Germanium Substrates. Silicon, 2016, 8, 345-350.	3.3	14
4	Investigation of Current Conduction Mechanism in HfO <sub>2</sub> Thin Film on Silicon Substrate. Environmental Science and Engineering, 2014, , 25-27.	0.2	2
5	Capacitance-Voltage Measurement of SiO <sub>2</sub> /GeO <sub>x</sub> N <sub>y</sub> Gate Stack on Surface Passivated Germanium. Environmental Science and Engineering, 2014, , 9-11.	0.2	0
6	Sol-gel deposited ceria thin films as gate dielectric for CMOS technology. Bulletin of Materials Science, 2013, 36, 259-263.	1.7	30
7	Structural and electrical characteristics of RF-sputtered HfO <sub>2</sub> high-k based MOS capacitors. Solid-State Electronics, 2011, 62, 44-47.	1.4	73